# **Schottky Barrier Diodes**

# NSR0320MW2T1G, NSVR0320MW2T1G

These Schottky barrier diodes are designed for high current, handling capability, and low forward voltage performance.

### **Features**

- Low Forward Voltage 0.24 Volts (Typ) @  $I_F = 10 \text{ mAdc}$
- High Current Capability
- ESD Rating:
  - ◆ Human Body Model: CLASS 3B
  - Machine Model: C
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

## **MAXIMUM RATINGS** (T<sub>J</sub> = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	20	Vdc
Peak Revese Voltage	V <sub>RM</sub>	23	V
Forward Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>F</sub>	200 2.0	mW mW/°C
Forward Current (DC) Continuous	IF	1	Α
Forward Current t = 8.3 ms Half Sinewave	I <sub>FSM</sub>	5	Α
Thermal Resistance, Junction-to-Ambient 175 mm <sup>2</sup> , 1 oz. Cu, FR-4	$R_{\theta JA}$	500	°C/W
Thermal Resistance, Junction-to-Lead 175 mm <sup>2</sup> , 1 oz. Cu, FR-4	$R_{ heta JL}$	322	°C/W
Junction Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



## ON Semiconductor®

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## HIGH CURRENT SCHOTTKY BARRIER DIODE



SOD-323 CASE 477 STYLE 1



## **MARKING DIAGRAM**



RD = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

Device	Package	Shipping†
NSR0320MW2T1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel
NSVR0320MW2T1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## NSR0320MW2T1G, NSVR0320MW2T1G

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Total Capacitance (V <sub>R</sub> = 5.0 V, f = 1.0 MHz)	C <sub>T</sub>	-	25	29	pF
Reverse Leakage (V <sub>R</sub> = 15 V) (V <sub>R</sub> = 2.0 V @ 85°C) (V <sub>R</sub> = 15.0 V @ 85°C)	I <sub>R</sub>	- - -	10 200 450	50 - -	μΑ
Forward Voltage (I <sub>F</sub> = 10 mA) (I <sub>F</sub> = 100 mA) (I <sub>F</sub> = 900 mA)	V <sub>F</sub>	- - -	0.24 0.30 0.45	0.27 0.35 0.50	V

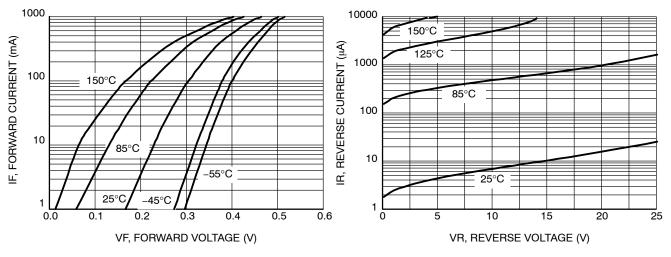


Figure 1. Forward Voltage

Figure 2. Leakage Current

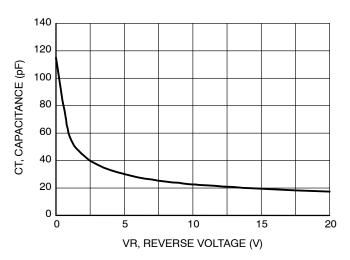
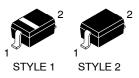


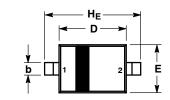
Figure 3. Total Capacitance

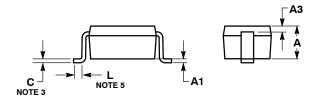


SOD-323 CASE 477-02 **ISSUE H** 

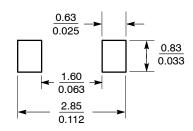
**DATE 13 MAR 2007** 

### SCALE 4:1





## **SOLDERING FOOTPRINT\***

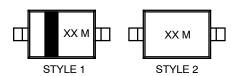


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.
  5. DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES		
DIN	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
E	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

## **GENERIC** MARKING DIAGRAM\*



XX = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

NO POLARITY

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